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Vishay Semiconductors

Standard Recovery Diodes, (Stud Version), 85 A



DO-5 (DO-203AB)

PRIMARY CHARACTERISTICS				
I _{F(AV)} 85 A				
Package	DO-5 (DO-203AB)			
Circuit configuration	Single			

FEATURES

- High surge current capability
- Stud cathode and stud anode version



- · Leaded version available
- Types up to 1600 V V_{RRM}
- · Designed and qualified for industrial level
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

- Battery chargers
- Converters
- Power supplies
- Machine tool controls
- Welding

MAJOR RATINGS AND CHARACTERISTICS					
PARAMETER	TEST COMPLETIONS	85H	LINUTO		
	TEST CONDITIONS	10 to 120	140 to 160	UNITS	
1		85	85	Α	
I _{F(AV)}	T _C	140	110	°C	
I _{F(RMS)}		133	133	Α	
1	50 Hz	1700	1700	٨	
IFSM	60 Hz	1800	1800	Α	
121	50 Hz	14 500	14 500	A 2 -	
I ² t	60 Hz	13 500	13 500	A ² s	
V_{RRM}	Range	100 to 1200	1400 to 1600	V	
T _J		-65 to +180	-65 to +150	°C	

ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS					
TYPE NUMBER	VOLTAGE CODE	V _{RRM} , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} MAXIMUM AT T _J = T _J MAXIMUM mA	
	10	100	200		
	20	200	300		
	40	400	500		
VS-85HF(R)	60	600	700	9	
VS-86HF(R) VS-87HF(R)	80	800	900		
VS-88HF(R)	100	1000	1100		
	120	1200	1300		
	140	1400	1500	4.5	
I	160	1600	1700	4.5	



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FORWARD CONDUCTION							
PARAMETER	SYMBOL	TEST CONDITIONS		85H	F(R)	UNITS	
PARAMETER	STWIBUL		TEST CONDITIONS		10 to 120	140/160	UNITS
Maximum average forward current	I _{F(AV)}	180° condu	uction, half sine	wave	8		Α
at case temperature	1 (AV)				140	110	°C
Maximum RMS forward current	I _{F(RMS)}				133		Α
		t = 10 ms	No voltage		1700		
Maximum peak, one-cycle forward,	1	t = 8.3 ms	reapplied	Sinusoidal half wave,	1800		A
non-repetitive surge current	I _{FSM}	t = 10 ms	100 % V _{RRM}		1450		
		t = 8.3 ms	reapplied		1500		
M 121 f f	l ² t	t = 10 ms	No voltage	initial $T_J = T_J$ maximum	14 500		- A ² s
		t = 8.3 ms	reapplied		13 500		
Maximum I ² t for fusing		t = 10 ms	100 % V _{RRM}		10 500		
		t = 8.3 ms	reapplied		9400		
Maximum I ² √t for fusing	I ² √t	t = 0.1 ms to 10 ms, no voltage reapplied		145	000	A²√s	
Value of threshold voltage (up to 1200 V)	- V _{F(TO)}	V	T. T. actions		0.	68	V
Value of threshold voltage (for 1400 V, 1600 V)		$T_J = T_J$ maximum			0.	69	ľ
Value of forward slope resistance (up to 1200 V)			$T_J = T_J$ maximum		1.62		mW
Value of forward slope resistance (for 1400 V, 1600 V)	- r _f	i j = i j maximum			1.	1.75	11100
Maximum forward voltage drop	V_{FM}	$I_{pk} = 267 \text{ A}, T_{J} = 25 \text{ °C}, t_{p} = 400 \mu \text{s rectangular wave}$ 1.2			1.4	V	

THERMAL AND MECHANICAL SPECIFICATIONS						
PARAMETER	CVMDOL	TEST CONDITIONS	85H	LINUTO		
PARAMETER	SYMBOL		10 to 20	140 to 160	UNITS	
Maximum junction operating and storage temperature range	T _J , T _{Stg}		-65 to +180	-65 to +150	°C	
Maximum thermal resistance, junction to case	R _{thJC}	DC operation	0.	0.35		
Maximum thermal resistance, case to heatsink	R _{thCS}	Mounting surface, smooth, flat and greased	0.25		K/W	
Maximum shock (1)			1500			
Maximum constant vibration (1)		50 Hz	20		g	
Maximum constant acceleration (1)		Stud outwards	50	000		
		Not lubricated thread, tighting on nut	3.4	(30)		
Maximum allowable mounting torque		Lubricated thread, tighting on nut	2.3 (20) 4.2 (37)		N⋅m	
+ 0 %, - 10 %		Not lubricated thread, tighting on hexagon			(lbf · in)	
		Lubricated thread, tighting on hexagon	3.2	(28)		
Approximate weight		I lalandad davias	1	7	g	
Approximate weight		Unleaded device	0	.6	oz.	
Case style		See dimensions - link at the end of datasheet DO-5 (DO-203A		-5 (DO-203AB)	

Notes

- (1) Available only for 88HF
- (2) Recommended for pass-through holes
- (3) Recommended for holed threaded heatsinks

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△R _{thJC} CONDUCTION					
CONDUCTION ANGLE	SINUSOIDAL CONDUCTION	RECTANGULAR CONDUCTION	TEST CONDITIONS	UNITS	
180°	0.10	0.08			
120°	0.11	0.11			
90°	0.13	0.13	$T_J = T_J$ maximum	K/W	
60°	0.17	0.17			
30°	0.26	0.26			

Note

• The table above shows the increment of thermal resistance RthJC when devices operate at different conduction angles than DC

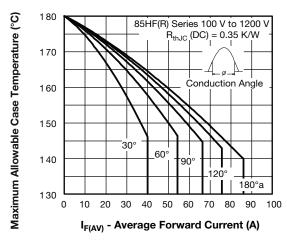


Fig. 1 - Current Ratings Characteristics

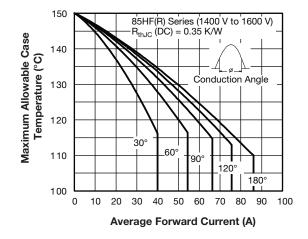


Fig. 3 - Current Ratings Characteristics

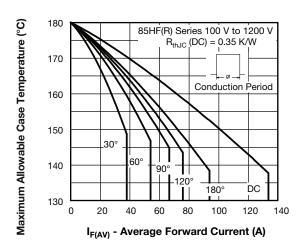


Fig. 2 - Current Ratings Characteristics

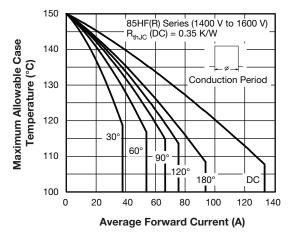


Fig. 4 - Current Ratings Characteristics

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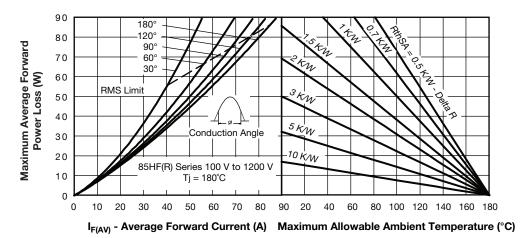
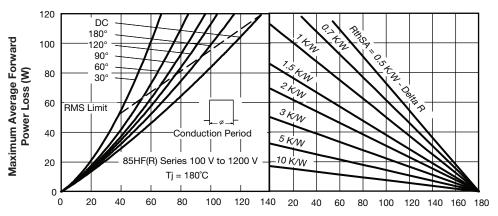


Fig. 5 - Forward Power Loss Characteristics



I_{F(AV)} - Average Forward Current (A) Maximum Allowable Ambient Temperature (°C)

Fig. 6 - Forward Power Loss Characteristics

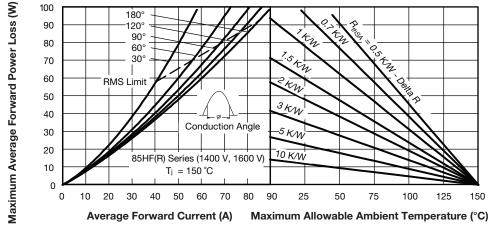


Fig. 7 - Forward Power Loss Characteristics

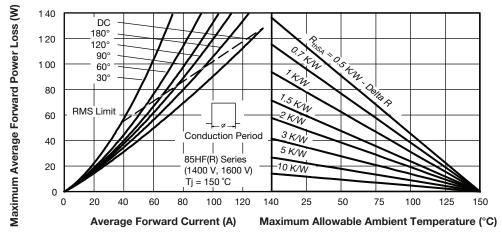


Fig. 8 - Forward Power Loss Characteristics

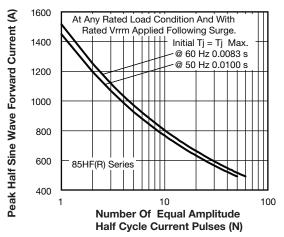


Fig. 9 - Maximum Non-Repetitive Surge Current

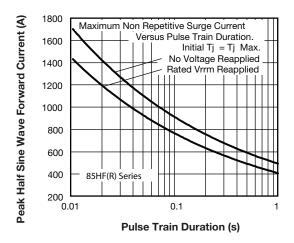


Fig. 10 - Maximum Non-Repetitive Surge Current

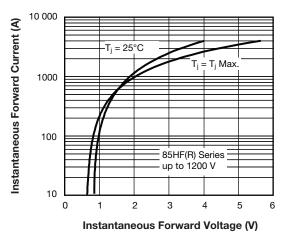


Fig. 11 - Forward Voltage Drop Characteristics

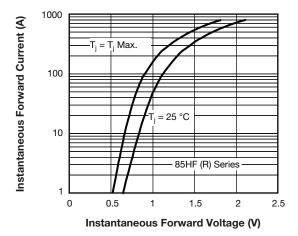


Fig. 12 - Forward Voltage Drop Characteristics (for 1400 V, 1600 V)

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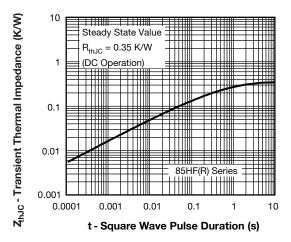
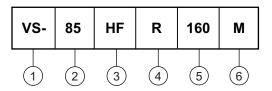


Fig. 13 - Thermal Impedance Z_{thJC} Characteristics

ORDERING INFORMATION TABLE





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2 - 85 = standard device

86 = not isolated lead

87 = isolated lead with silicone sleeve

(red = Reverse polarity)

(blue = Normal polarity)

88 = type for rotating application

3 - HF = standard diode

4 - None = stud normal polarity (cathode to stud)

R = stud reverse polarity (anode to stud)

5 - Voltage code x 10 = V_{RRM} (see Voltage Ratings table)

None = stud base DO-5 (DO-203AB) 1/4" 28UNF-2A

M = stud base DO-5 (DO-203AB) M6 x 1 (not available for 88HF)

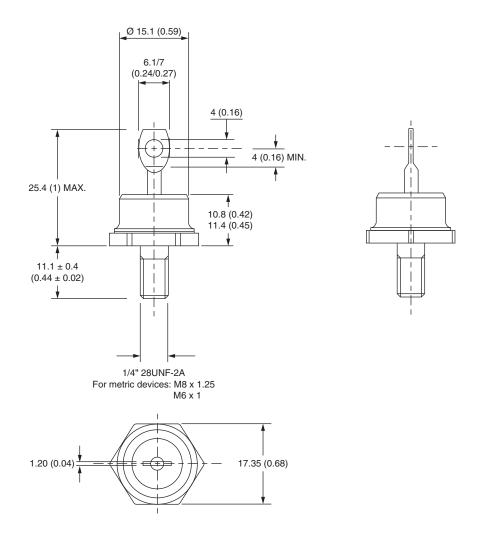
M8 = stud base DO-5 (DO-203AB) M8 x 1.25 (not available for 88HF)

LINKS TO RELATED DOCUMENTS			
Dimensions	www.vishay.com/doc?95342		

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DO-5 (DO-203AB) for 85HF(R), 86HF(R) and 88HF(R)Series

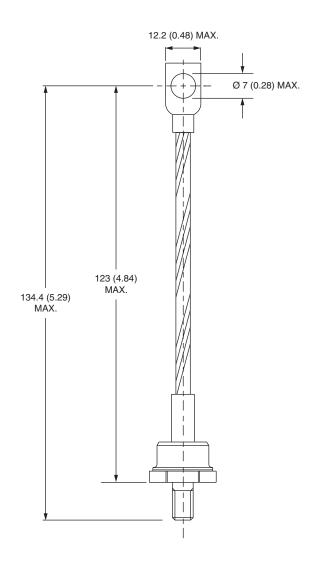
DIMENSIONS FOR 85HF(R) SERIES in millimeters (inches)





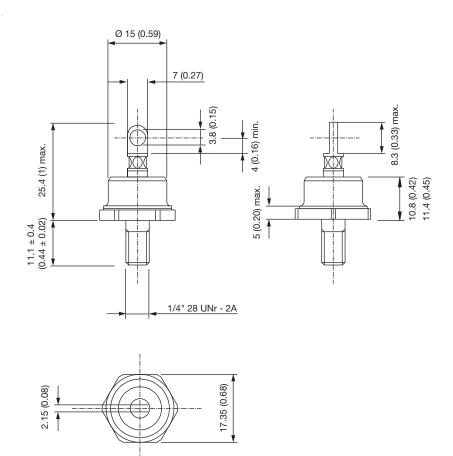
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DIMENSIONS FOR 86HF(R) SERIES in millimeters (inches)



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DIMENSIONS 88HF(R) SERIES in millimeters (inches)





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